NSN 5962-01-347-8622

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View Online at https://aerobasegroup.com/nsn/5962-01-347-8622

view Offiline at https://aerobasegroup.com/nsn/0302-01-04/1-0022
Body Length:
Between 0.442 inches and 0.460 inches
Body Width:
Between 0.442 inches and 0.460 inches
Body Height:
Between 0.060 inches and 0.100 inches
Maximum Power Dissipation Rating:
550.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmable and monolithic and w/disable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
11 input
Case Outline Source And Designator:
C-4 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
One time programmable prom
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds access
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
28 leadless
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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